

Lecture 1 - Electrons, Photons and Phonons

September 4, 2002

Contents:

1. Electronic structure of semiconductors
2. Electron statistics
3. Lattice vibrations
4. Thermal equilibrium

Reading assignment:

del Alamo, Ch. 1

Announcements:

Tomorrow's recitation slot will be used as lecture (in exchange for lecture slot in December that will be used as recitation).

Go to <http://weblab.mit.edu> and register. Put "6.720 student" in the Description field.

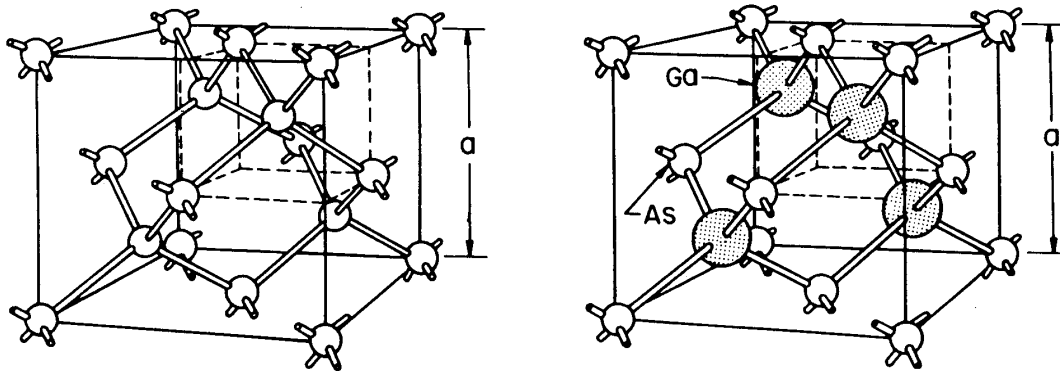
Key questions

- What makes semiconductors so special?
- How do electrons arrange themselves (in energy) in an electronic system?
- Why should we be concerned with the vibrational modes of the lattice of a crystalline solid?
- What is the formal definition of thermal equilibrium? What are some of its consequences?

1. Semiconductors as solids

□ Semiconductors are crystalline solids

Crystalline solid = elemental atomic arrangement, or *unit cell*, repeated ad infinitum in space in three dimensions.



- Si lattice constant: 0.54 nm
- Si atomic spacing: 0.24 nm
- Si atomic density: $5.0 \times 10^{22} \text{ cm}^{-3}$

Semiconductors held together by *covalent bonding* \Rightarrow 4 valence electrons shared with 4 neighbours \Rightarrow low energy situation.

	IIIA	IVA	VA	VIA
	⁵ B	⁶ C	⁷ N	⁸ O
	¹³ Al	¹⁴ Si	¹⁵ P	¹⁶ S
IIIB	³⁰ Zn	³¹ Ga	³² Ge	³³ As
	⁴⁸ Cd	⁴⁹ In	⁵⁰ Sn	⁵¹ Sb
			⁵² Te	

□ Solid is electronic system with *periodic potential*

Fundamental result of solid-state physics: *quantum states cluster in bands leaving bandgaps* (regions without allowed states) *in between*.



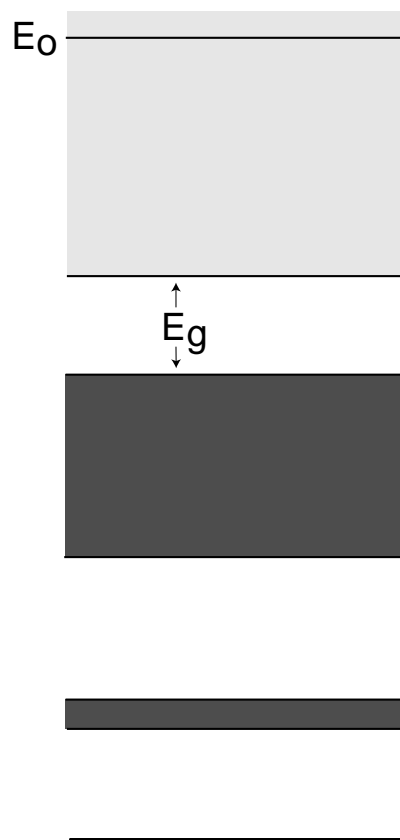
□ Semiconductor band structure

There are many more quantum states than electrons in a solid.

Quantum states filled with one electron per state starting from lowest energy state (*Pauli exclusion principle*).

Distinct feature of semiconductors:

At 0 K , filling ends up with full band separated by 1 – 3 eV bandgap from next empty band \Rightarrow At around 300 K , some electrons populate next band above bandgap.



2. Electron statistics

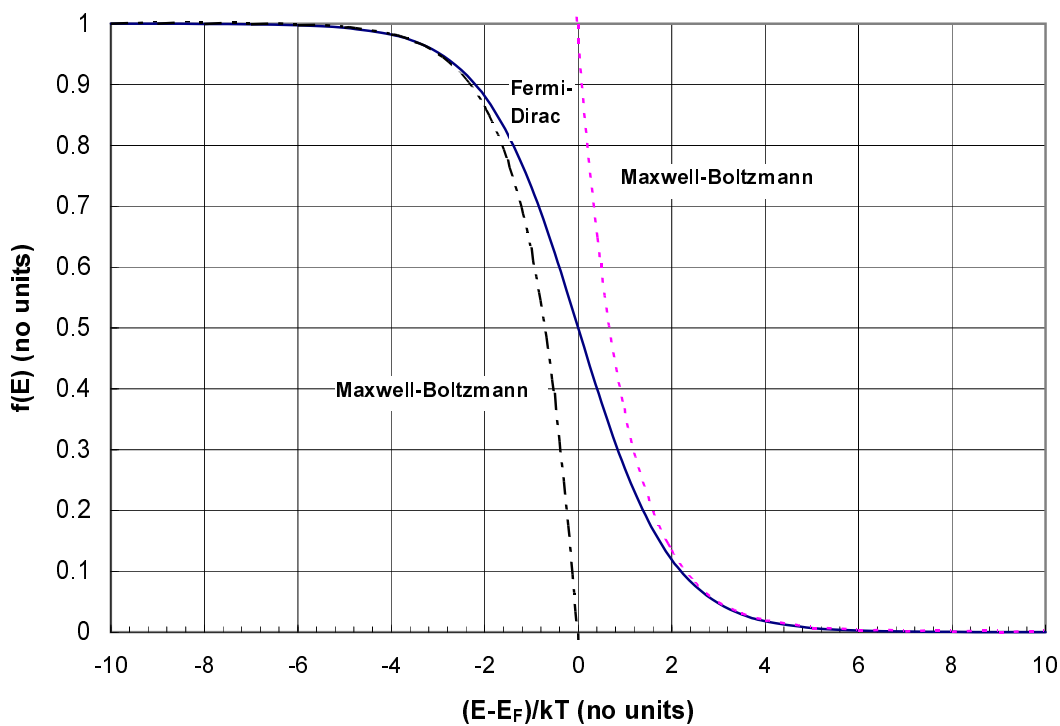
At finite temperature, state occupation probability by electron determined by **Fermi-Dirac distribution function**:

$$f(E) = \frac{1}{1 + \exp \frac{E - E_F}{kT}}$$

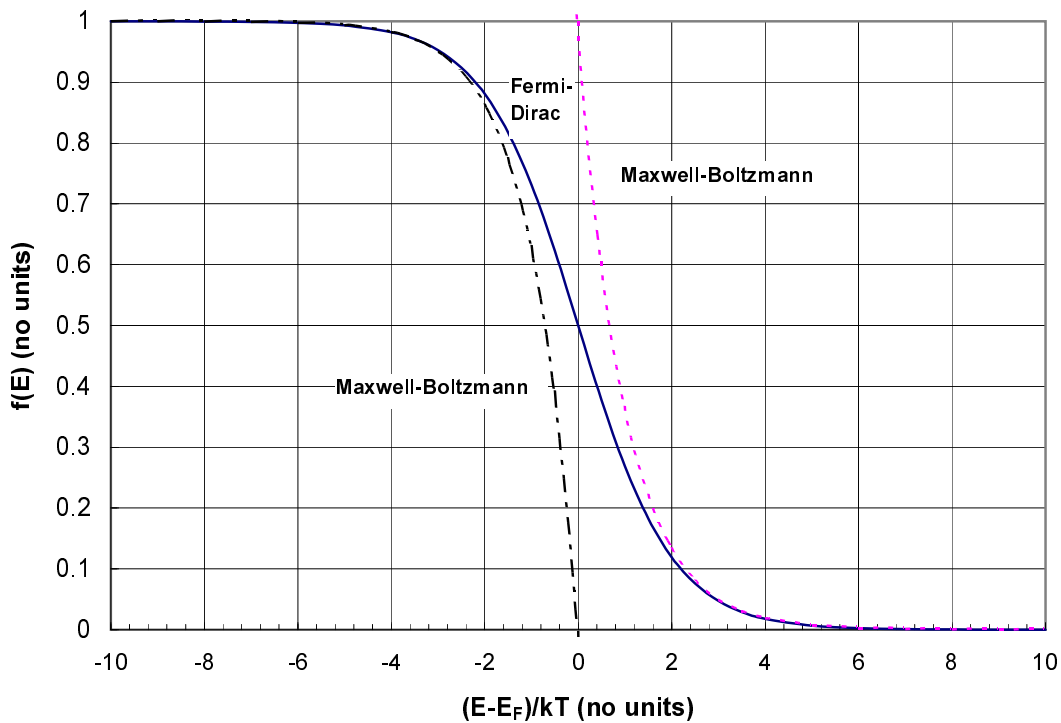
$E_F \equiv$ *Fermi energy* \equiv energy for which occupation probability is 50%

$k \equiv$ *Boltzmann constant* $= 8.62 \times 10^{-5} \text{ eV/K}$

$kT \equiv$ *thermal energy* $= 25.9 \text{ meV @ } 300 \text{ K}$

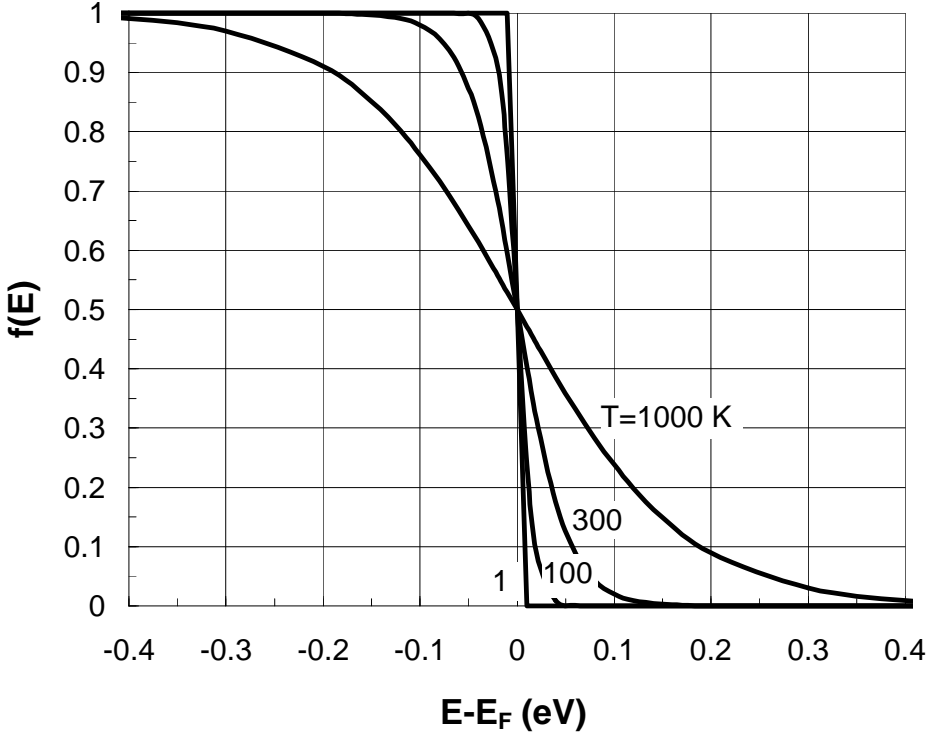


Properties of Fermi-Dirac distribution function:



- for $E \ll E_F$: $f(E) \simeq 1$
- for $E \gg E_F$: $f(E) \simeq 0$
- width of transition around $E_F \simeq 3kT$ (20% criterium)
- symmetry: $f(E_F + E_1) = 1 - f(E_F - E_1)$

Temperature dependence of Fermi-Dirac distribution function:



In general, E_F function of T.

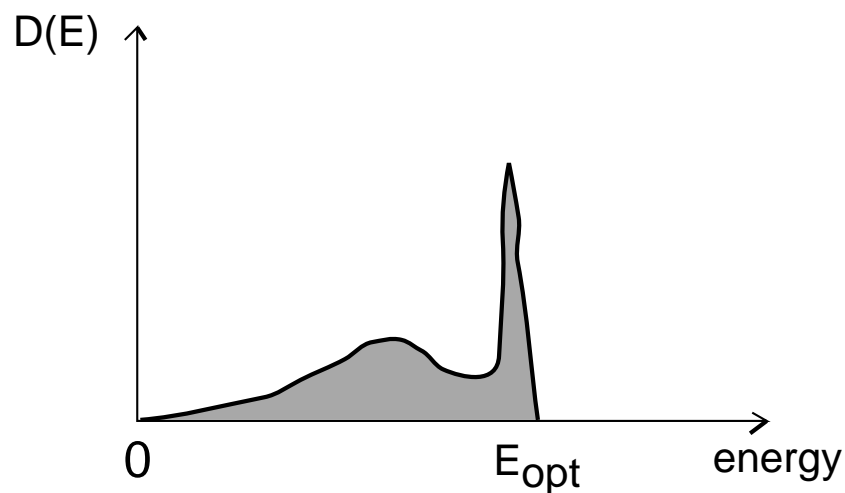
3. Lattice vibrations

At finite T atoms in lattice vibrate.

Solid is large coupled system \rightarrow only certain vibrational modes are possible.

Each vibrational mode is characterized by its mechanical energy.

Define *density of modes*:



- few modes at low energies (*acoustical modes*)
- many modes at a certain energy E_{opt} (*optical modes*)
- no modes beyond E_{opt}

For Si: $E_{opt} = 63 \text{ meV}$.

□ Lattice can exchange energy with electrons in the solid:

- an electron can give some energy to the lattice: excites an available vibrational mode
- an electron can acquire energy from lattice: a vibrational mode is extinguished

Easy to think of vibrational modes as particles: **phonons**.

Then talk about:

- phonon emission by an electron
- phonon absorption by an electron

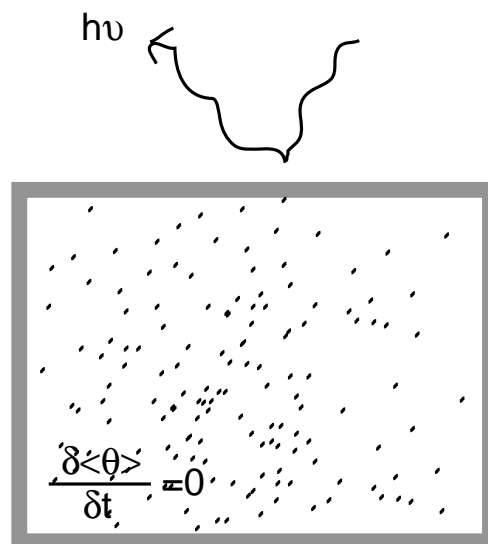
Similarly with **photons** or quanta of light.

Photon and phonon emission and absorption are important energy exchange mechanisms in semiconductors.

4. Thermal equilibrium

A particle system is in thermal equilibrium if:

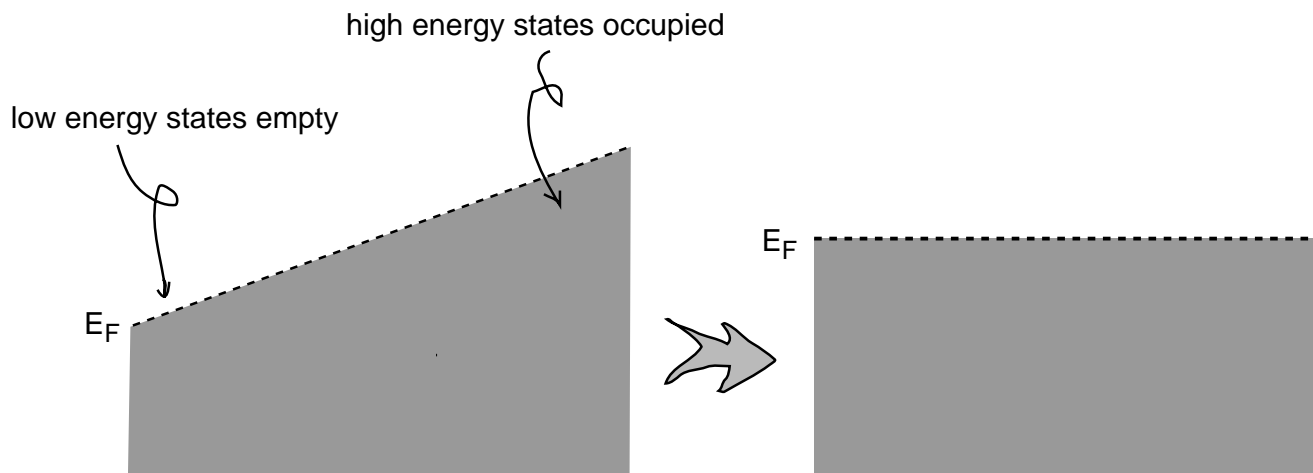
- it is *closed*: no energy flow through boundaries of system
- it is in *steady-state*: time derivatives of all ensemble averages (global and local) are zero



Thermal equilibrium important because all systems evolve towards TE after having been perturbed.

In order to know how a system evolves, it is essential to know where it is going.

□ In thermal equilibrium, E_F constant throughout system



Key conclusions

- In solids, electron states cluster in bands separated by bandgaps.
- Distinct feature of semiconductors: at 0 K , quantum state filling ends up with full band separated from next empty band by 1 – 3 eV bandgap \Rightarrow at around 300 K , some electrons populate next band above bandgap.
- Occupation probability of quantum systems in thermal equilibrium governed by *Fermi-Dirac distribution function*:

$$f(E) = \frac{1}{1 + \exp \frac{E - E_F}{kT}}$$

- Electrons can exchange energy with *photons* (quanta of light) and with *phonons* (quanta of vibrational energy of lattice).
- System in *thermal equilibrium*: isolated from outside world + in steady state.
- In thermal equilibrium, E_F is independent of position.
- Order of magnitude of key parameters:
 - atomic density of Si: $N_{Si} \sim 5 \times 10^{22} \text{ cm}^{-3}$
 - bandgap of Si: $E_g \sim 1 \text{ eV}$
 - thermal energy: $kT \sim 26 \text{ meV}$ @ 300K
 - optical phonon energy of Si: $E_{opt} \sim 60 \text{ meV}$

Self-study

- Concept of *blackbody radiation*.
- Concept of *vacuum energy*.
- Concept of *density of states*.
- Understand how can the Fermi energy change with temperature.
- *Maxwell-Boltzmann distribution function*.